COMPLIANT

HALOGEN

FREE



Vishay Semiconductors

High Performance Schottky Rectifier, 3 A



DO-214AC (SMA)

PRODUCT SUMMARY				
Package	DO-214AC (SMA)			
I _{F(AV)}	3 A			
V_{R}	40 V			
V _F at I _F	0.46 V			
I _{RM}	20 mA at 125 °C			
T _J max.	150 °C			
Diode variation	Single die			
E _{AS}	6.0 mJ			

FEATURES

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability
- · Small footprint, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Switching power supplies
- Meter protection
- Reverse protection for power input to PC board circuits
- Battery isolation and charging
- · Low threshold voltage diode
- Freewheeling or by-pass diode
- Low voltage clamp

DESCRIPTION

The VS-30MQ040HM3 Schottky rectifier is designed to be used for low power applications where a reverse voltage of 40 V is encountered and surface mountable is required.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I _{F(AV)}	Rectangular waveform	3	А	
V _{RRM}		40	V	
I _{FSM}	t _p = 5 μs sine	330	А	
V _F	2 A _{pk} , T _J = 125 °C	0.43	V	
T _J	Range	-40 to +150	°C	

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-30MQ040HM3	UNITS	
Maximum DC reverse voltage	V_{R}	40	V	
Maximum working peak reverse voltage	V_{RWM}	40	V	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 4	I _{F(AV)}	$50~\%$ duty cycle at $T_L = 89~^{\circ}$ C, re On PC board 9 mm² island (0.013 mm thick copper pad area	· ·	3	Α
Maximum peak one cycle non-repetitive surge current		5 μs sine or 3 μs rect. pulse	Following any rated	330	Α
See fig. 6	I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	140	A
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 12 mH		6.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1.0	Α



Vishay Semiconductors

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
		1 A	T _J = 25 °C	0.42	V
Maximum forward voltage drop	V _{FM} ⁽¹⁾	3 A		0.51	
See fig. 1	V FM (1)	1 A	T _J = 125 °C	0.34	
		3 A		0.46	
Maximum reverse leakage current		T _J = 25 °C	V _B = Rated V _B	0.5	- mA
See fig. 2	I _{RM}	T _J = 125 °C	VR = nated VR	20	
Threshold voltage	V _{F(TO)}	$T_{J} = T_{J} \text{ maximum} $ 0.26 64.6		0.26	V
Forward slope resistance	r _t			64.6	mΩ
Typical junction capacitance	C _T	$V_R = 10 V_{DC}$, $T_J = 25 °C$, test signal = 1 MHz		134	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body 2.0		nH	
Maximum voltage rate of change	dV/dt	Rated V _R 10 000		V/µs	

Note

 $^{(1)}\,$ Pulse width = 300 $\mu s,$ duty cycle = 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		-40 to +150	°C
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	°C/W
Approximate weight			0.07	g
Approximate weight			0.002	OZ.
Marking device		Case style SMA (similar D-64)	3	F

Note

(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink



www.vishay.com

Vishay Semiconductors

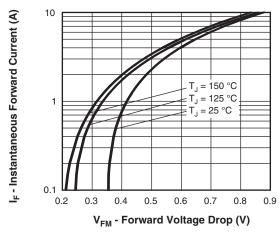


Fig. 1 - Maximum Forward Voltage Drop Characteristics

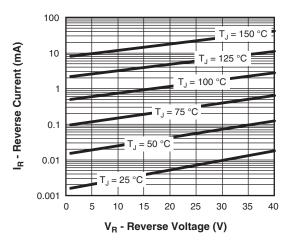


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

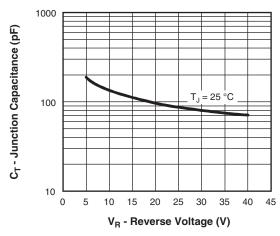
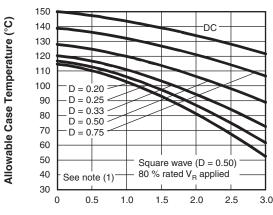
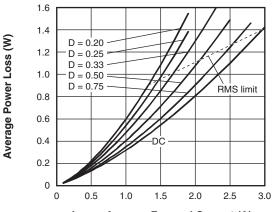


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



I_{F(AV)} - Average Forward Current (A)

Fig. 4 - Maximum Average Forward Current vs.
Allowable Lead Temperature



I_{F(AV)} - Average Forward Current (A)

Fig. 5 - Maximum Average Forward Dissipation vs. Average Forward Current

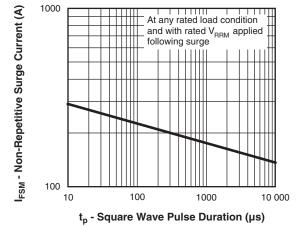


Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

Note

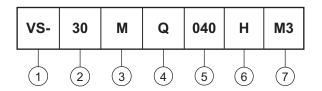
(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R$ (1 - D); I_R at $V_{R1} = 80$ % rated V_R



Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Current rating
- 3 M = SMA
- 4 Q = Schottky "Q" series
- 5 Voltage rating (040 = 40 V)
- 6 H = AEC-Q101 qualified
- 7 Environmental digit:

M3 = Halogen-free, RoHS-compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)				
PREFERRED P/N	PREFERRED PACKAGE CODE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION			
VS-30MQ040HM3/5AT	5AT	7500	13" diameter plastic tape and reel	

LINKS TO RELATED DOCUMENTS			
Dimensions www.vishay.com/doc?95400			
Part marking information <u>www.vishay.com/doc?95403</u>			
Packaging information	www.vishay.com/doc?95404		

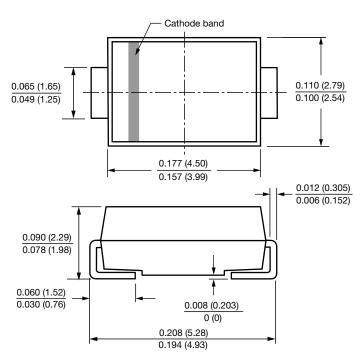


Vishay Semiconductors

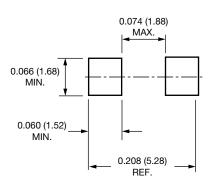
SMA

DIMENSIONS in inches (millimeters)

DO-214AC (SMA)



Mounting Pad Layout





Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.